Onsemi

NPN Epitaxial Silicon Transistor

BC337

Features

- Switching and Amplifier Applications
- Suitable for AF-Driver Stages and Low-Power Output Stages
- Complement to BC327/BC328

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
V _{CES}	Collector-Emitter Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
۱ _C	Collector Current (DC)	800	mA
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	–55 to +150	°C

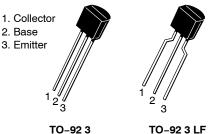
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$ (Note 1)

Symbol	Characteristic	Value	Unit
PD	Power Dissipation Derate Above 25°C	625 5.0	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

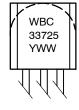
PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) 1. with minimum land pattern size.



CASE 135AN

TO-92 3 LF CASE 135AR

MARKING DIAGRAM



WBC = Assembly Location 33725

- = Specific Device Code
- = Year
- WW = Work Week

Y

ORDERING INFORMATION

Device	Package	Shipping [†]
BC33740BU	TO–92 3 (Pb–Free)	10,000 Units / BLKBG
BC33725BU	TO–92 3 (Pb–Free)	10,000 Units / BLKBG
BC33716BU	TO–92 3 (Pb–Free)	10,000 Units / BLKBG
BC33740TA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD
BC33725TA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD
BC33725TAR	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD
BC33716TA	TO–92 3 LF (Pb–Free)	2,000 Units / FNFLD
BC33725TF	TO–92 3 LF (Pb–Free)	2,000 / Tape & Reel
BC33725TFR	TO-92 3 LF (Pb-Free)	2,000 / Tape & Reel
BC33716TFR	TO-92 3 LF (Pb-Free)	2,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

BC337

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA, I _B = 0	45	-	-	V
BV _{CES}	Collector-Emitter Breakdown Voltage	I _C = 0.1 mA, V _{BE} = 0	50	-	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 0.1 mA, I _C = 0	5	-	-	V
I _{CES}	Collector Cut-Off Current	$V_{CE} = 45 \text{ V}, \text{ I}_{B} = 0$	-	2	100	nA
h _{FE1}	DC Current Gain	V _{CE} = 1 V, I _C = 100 mA	100	-	630	
h _{FE2}]	$V_{CE} = 1 \text{ V}, I_{C} = 300 \text{ mA}$	60	-		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA	-	-	0.7	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 1 V, I_C = 300 mA$	-	-	1.2	V
f _T	Current Gain Bandwidth Product	V_{CE} = 5 V, I _C = 10 mA, f = 50 MHz	-	100	-	MHz
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	12	_	pF

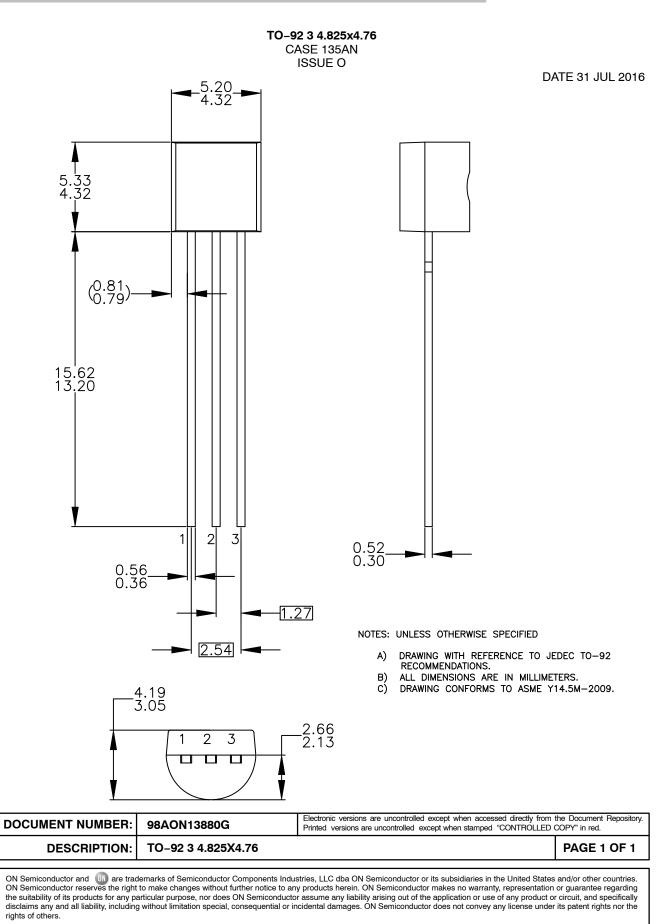
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted.)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

h_{FE} Classification

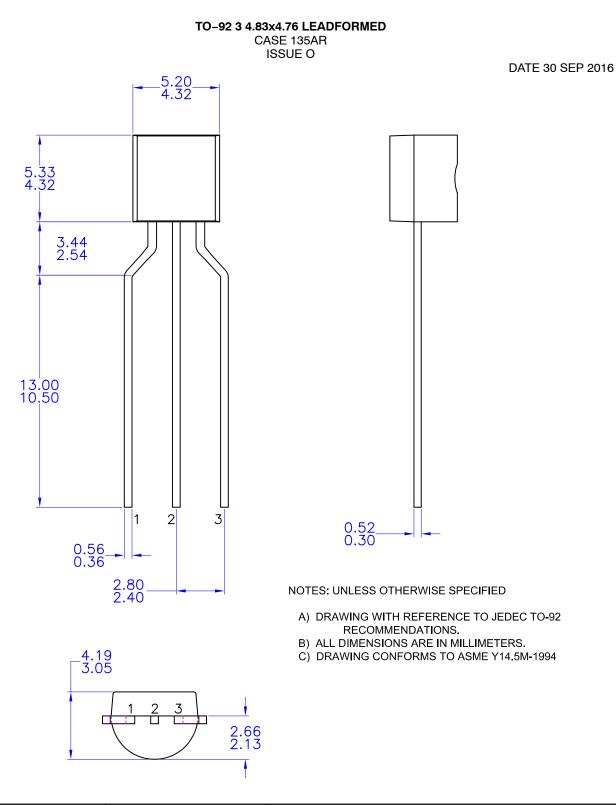
Classification	16	25	40
h _{FE1}	100 ~ 250	160 ~ 400	250 ~ 630
h _{FE2}	60 ~	100 ~	170 ~





© Semiconductor Components Industries, LLC, 2019





DOCUMENT NUMBER:	98AON13879G Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	TO-92 3 4.83X4.76 LEADFORMED		PAGE 1 OF 1		
ON Semiconductor and 🕅 are trademarks of Semiconductor Components Industries. LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.					

ON Semiconductor and ware trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>